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Information Disclosure Statement By Applicant (Use as many sheets as necessary)				Filing Date:	March 31, 2004
				First Named Inventor:	Katrina MIKHAYLICHENKO
				Art Unit:	1763
				Examiner Name:	S. Macarthur
				Attorney Docket Number:	LAM2P451
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Examiner Signature	/Sylvia Macarthur/	Date Considered	11/12/2007
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